

**COMPLEMENTARY OUTPUT HALL EFFECT LATCH****AH277A****General Description**

The AH277A is an integrated Hall sensor with output driver designed for electronic commutation of brushless DC motor applications. The device includes an on-chip Hall sensor for magnetic sensing, an amplifier that amplifies the Hall voltage, a Schmitt trigger to provide switching hysteresis for noise rejection, a temperature compensation circuit to compensate the temperature drift of Hall sensitivity and two complementary open-collector drivers for sinking large load current. It also includes an internal band-gap regulator which is used to provide bias voltage for internal circuits.

Placing the device in a variable magnetic field, if the magnetic flux density is larger than threshold B_{OP} , the pin DO will be turned low (on) and pin DOB will be turned high (off). This output state is held until the magnetic flux density reverses and falls below B_{RP} , then causes DO to be turned high (off) and DOB turned low (on).

AH277A is available in TO-94 (SIP-4L) package.

Features

- On-Chip Hall Sensor
- 3.5V to 16V Supply Voltage
- 400mA (avg) Output Sink Current
- Reversed Supply Voltage Protection
- -20°C to 85°C Operating Temperature
- Low Profile TO-94 (SIP-4L) Package
- ESD Rating: 300V (Machine Model)

Applications

- Dual-Coil Brushless DC Motor
- Dual-Coil Brushless DC Fan
- Revolution Counting
- Speed Measurement

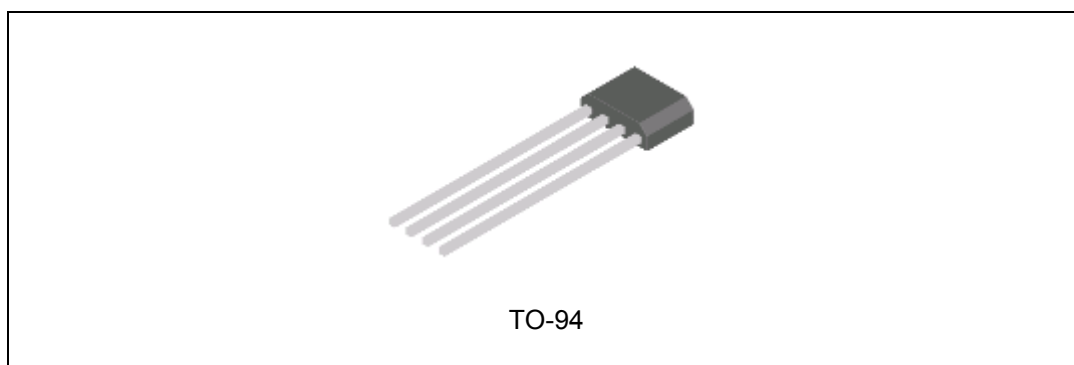


Figure 1. Package Type of AH277A

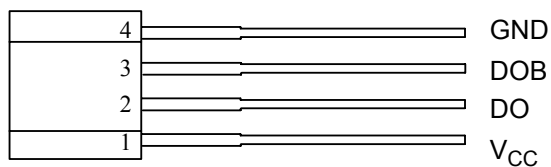
**COMPLEMENTARY OUTPUT HALL EFFECT LATCH****AH277A****Pin Configuration**Z4 Package
(TO-94)

Figure 2. Pin Configuration of AH277A (Front View)

Pin Description

Pin Number	Pin Name	Function
1	V _{CC}	Supply voltage
2	DO	Output 1
3	DOB	Output 2
4	GND	Ground

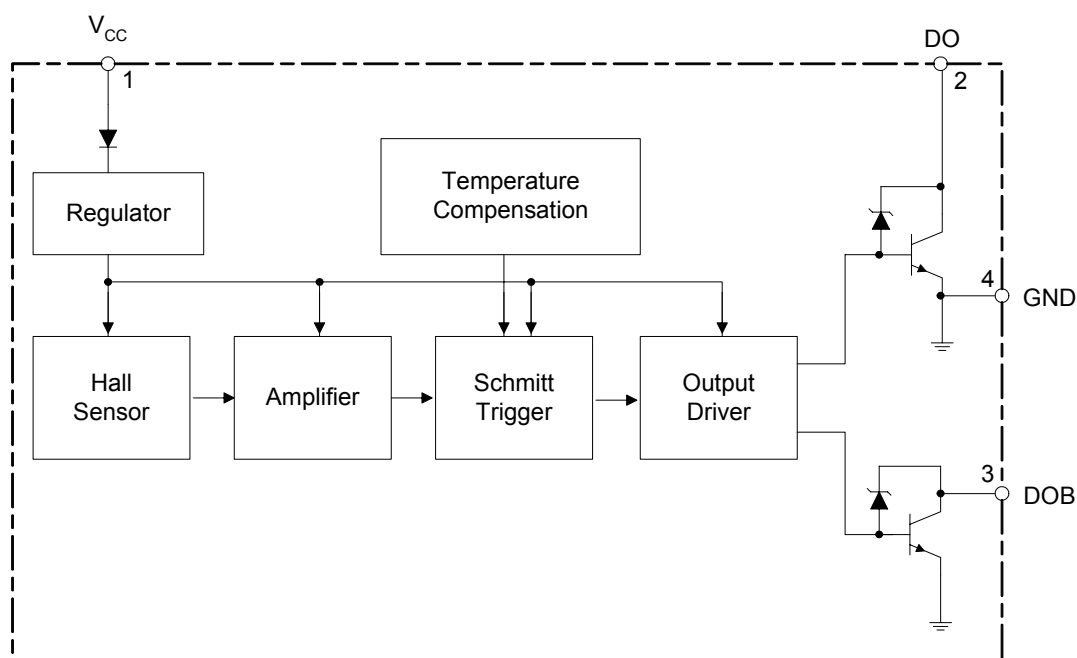
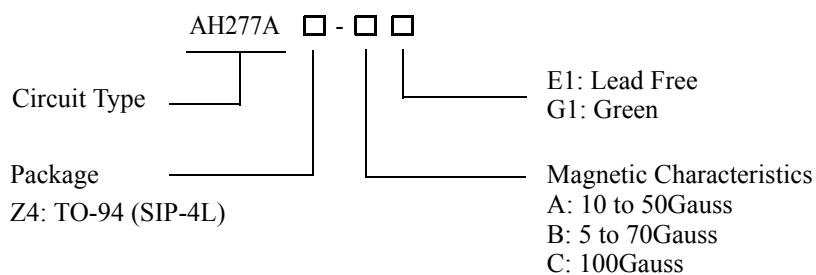
**COMPLEMENTARY OUTPUT HALL EFFECT LATCH****AH277A****Functional Block Diagram**

Figure 3. Functional Block Diagram of AH277A

Ordering Information

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
TO-94	-20 to 85°C	AH277AZ4-AE1	AH277AZ4-AG1	AH277A	AH277A-G1	Bulk
		AH277AZ4-BE1	AH277AZ4-BG1	AH277A	AH277A-G1	Bulk
		AH277AZ4-CE1	AH277AZ4-CG1	AH277A	AH277A-G1	Bulk

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green package.

**COMPLEMENTARY OUTPUT HALL EFFECT LATCH****AH277A****Absolute Maximum Ratings (Note 1)**(T_A=25°C)

Parameter		Symbol	Value	Unit
Supply Voltage		V _{CC}	20	V
Reverse Protection Voltage		V _{RCC}	-20	V
Magnetic Flux Density		B	Unlimited	Gauss
Output Current	Continuous	I _O	400	mA
	Hold		600	mA
	Peak (start up)		800	mA
Power Dissipation		P _D	550	mW
Thermal Resistance	Die to atmosphere	θ _{JA}	227	°C/W
	Die to package case	θ _{JC}	49	°C/W
Storage Temperature		T _{STG}	-50 to 150	°C
ESD (Machine Model)			300	V
ESD (Human Body Model)			2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. "Absolute Maximum Ratings" for extended period may affect device reliability.

Recommended Operating Conditions(T_A=25°C)

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	3.5	16	V
Ambient Temperature	T _A	-20	85	°C



COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Electrical Characteristics

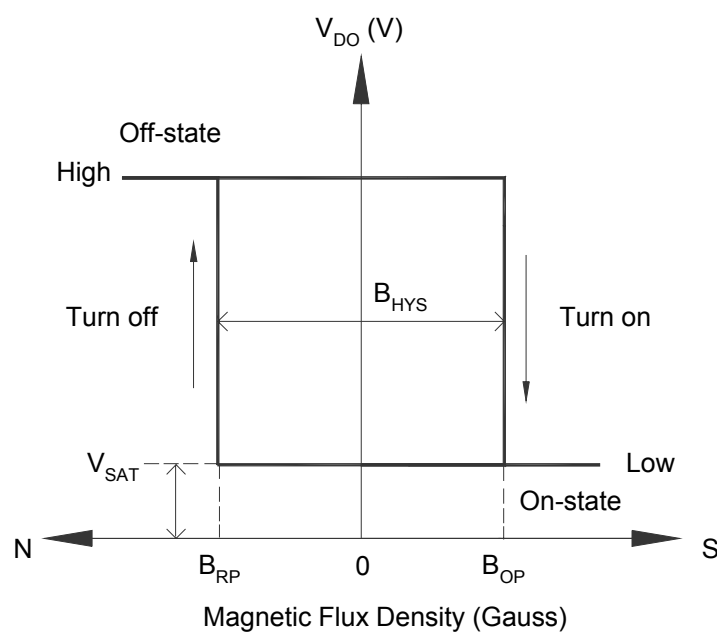
($T_A=25^{\circ}\text{C}$, $V_{CC}=14\text{V}$, unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Saturation Voltage	V_{SAT}	$V_{CC}=3.5\text{V}$, $I_O=100\text{mA}$		0.4		V
		$I_O=400\text{mA}$		0.35	0.6	V
Output Leakage Current	I_{OL}	$V_{CE}=16\text{V}$		0.1	10	μA
Supply Current	I_{CC}	$V_{CC}=16\text{V}$, Output Open		12	16	mA
Output Rise Time	t_r	$R_L=820\Omega$, $C_L=20\text{pF}$		3.0	10	μs
Output Fall Time	t_f	$R_L=820\Omega$, $C_L=20\text{pF}$		0.3	1.5	μs
Switch Time Differential	Δt	$R_L=820\Omega$, $C_L=20\text{pF}$		3.0	10	μs
Output Zener Breakdown Voltage	V_Z			55		V

Magnetic Characteristics

($T_A=25^{\circ}\text{C}$)

Parameter	Symbol	Grade	Min	Typ	Max	Unit
Operating Point	B_{OP}	A	10	30	50	Gauss
		B	5		70	Gauss
		C			100	Gauss
Releasing Point	B_{RP}	A	-50	-30	-10	Gauss
		B	-70		-5	Gauss
		C	-100			Gauss
Hysteresis	B_{HYS}			60		Gauss



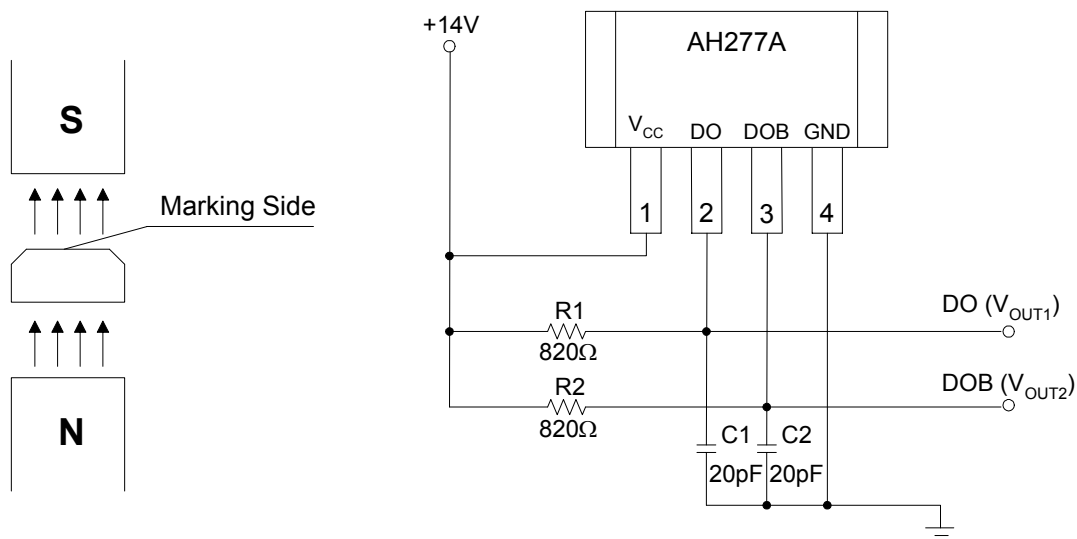
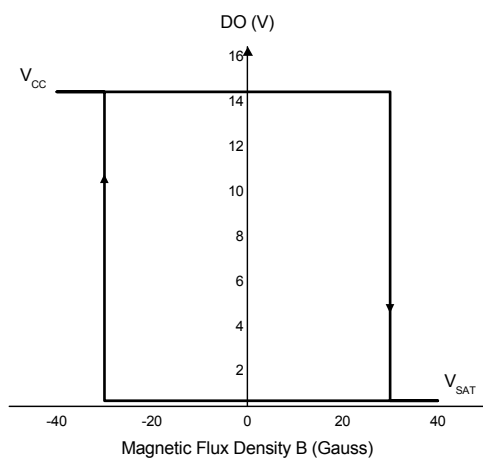
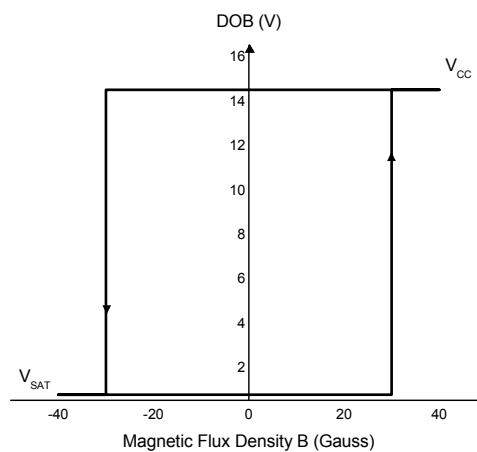
COMPLEMENTARY OUTPUT HALL EFFECT LATCH
AH277A
Magnetic Characteristics (Continued)


Figure 4. Basic Test Circuit


Figure 5. V_{DO} vs. Magnetic Flux Density

Figure 6. V_{DOB} vs. Magnetic Flux Density



COMPLEMENTARY OUTPUT HALL EFFECT LATCH

AH277A

Typical Performance Characteristics

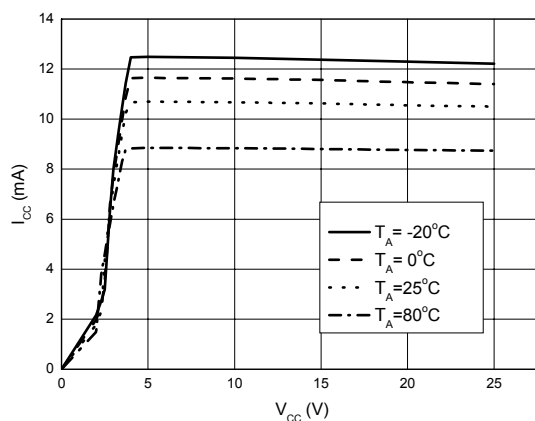


Figure 7. I_{CC} vs. V_{CC}

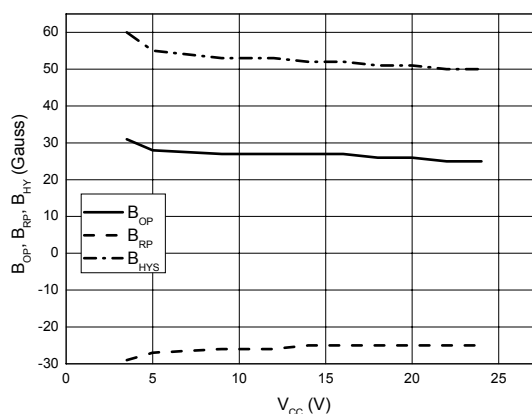


Figure 8. $B_{OP}/B_{RP}/B_{HYS}$ vs. V_{CC}

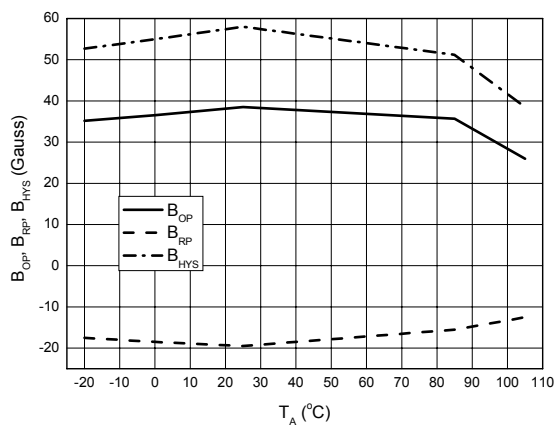


Figure 9. $B_{OP}/B_{RP}/B_{HYS}$ vs. Ambient Temperature

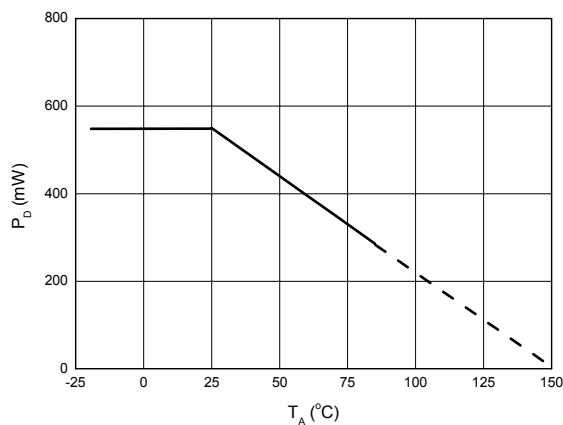


Figure 10. P_D vs. Ambient Temperature

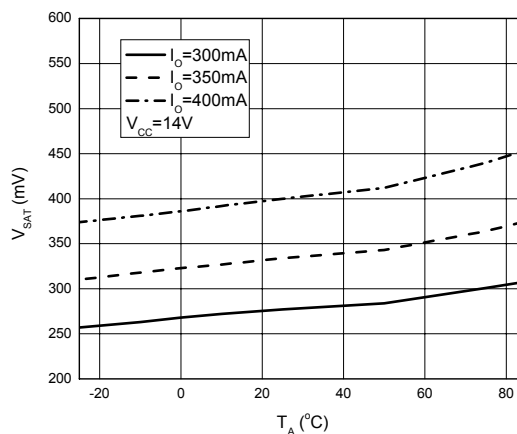
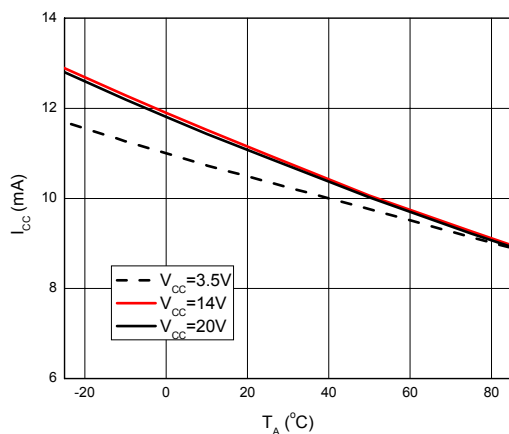
**COMPLEMENTARY OUTPUT HALL EFFECT LATCH****AH277A****Typical Performance Characteristics (Continued)**

Figure 11. Supply Current vs. Ambient Temperature

Figure 12. Saturation Voltage vs. Ambient Temperature

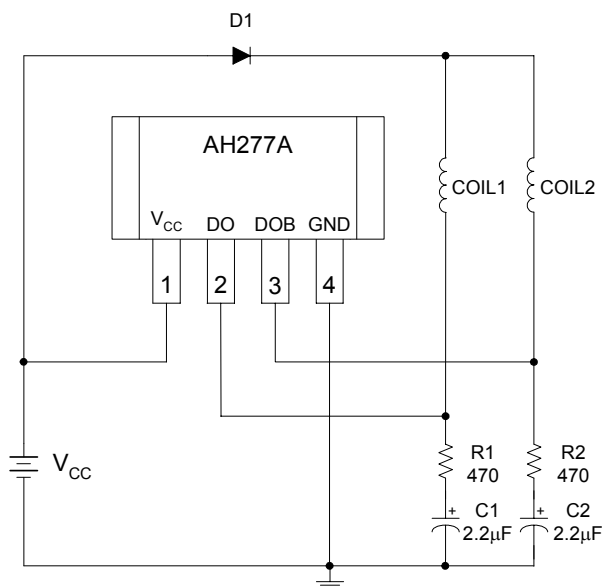
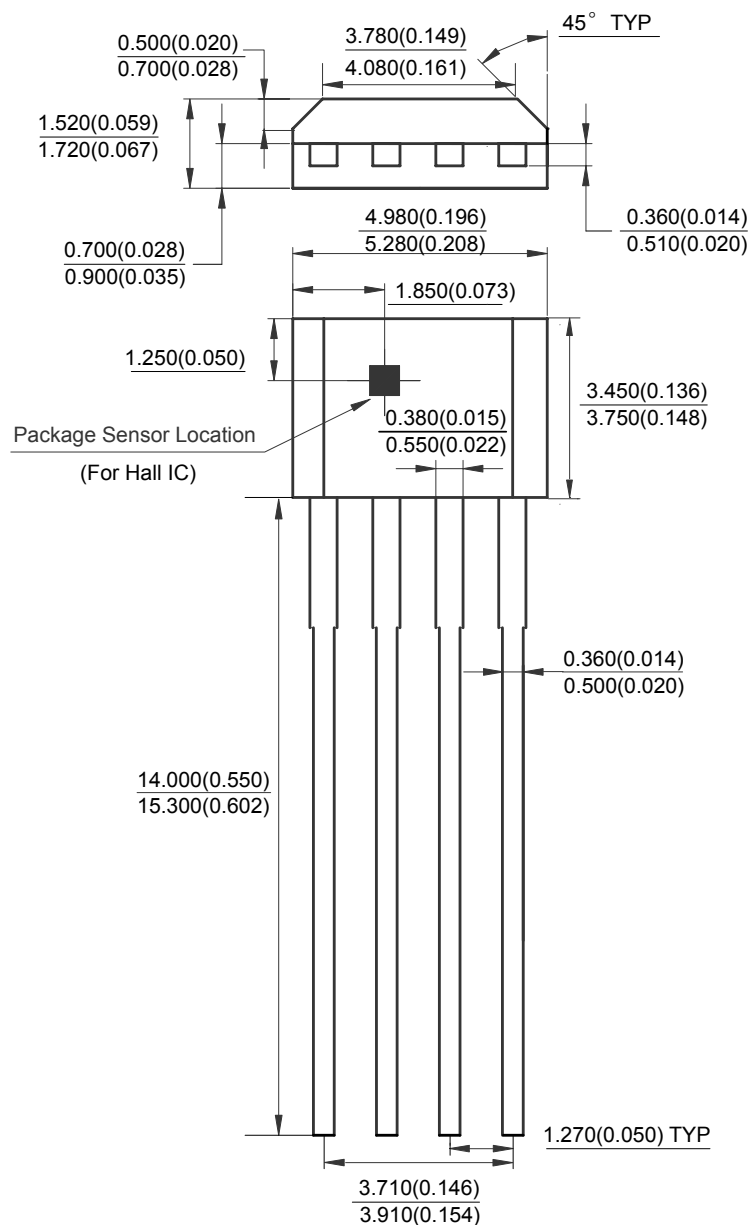
Typical Applications

Figure 13. Typical Application Circuit with D1(Note 2)

Note 2: AH277A has Reversed Supply Voltage Protection. For DC fan application, sometimes need to test power reverse connection condition. The internal diode only protects chip-side but not for coil-side. It is recommended to add one external diode D1 in application to block the reverse current from coil-side as shown in Figure 13.

**COMPLEMENTARY OUTPUT HALL EFFECT LATCH****AH277A****Mechanical Dimensions****TO-94****Unit: mm(inch)**



BCD Semiconductor Manufacturing Limited

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